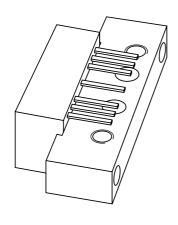
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## **BGY883** 860 MHz, 15 dB gain push-pull amplifier

Product specification Supersedes data of 1997 Apr 14

2001 Oct 31





### 860 MHz, 15 dB gain push-pull amplifier

**BGY883** 

#### **FEATURES**

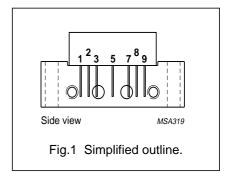
- · Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

### **DESCRIPTION**

Hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115J**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	14.5	15.5	dB
		f = 860 MHz	15	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	235	mA

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

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#### **CHARACTERISTICS**

**Table 1** Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,^{\circ}\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	14.5	_	15.5	dB
		f = 860 MHz	15	_	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	_	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	_	±0.3	dB
s <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	18.5	_	_	dB
		f = 160 to 320 MHz	17	_	_	dB
		f = 320 to 640 MHz	15.5	_	_	dB
		f = 640 to 860 MHz	14	_	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	18.5	_	_	dB
		f = 160 to 320 MHz	17	_	_	dB
		f = 320 to 640 MHz	15.5	_	_	dB
		f = 640 to 860 MHz	14	_	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	_	_	-61	dB
X <sub>mod</sub>	cross modulation	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	_	-61	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	-	_	-61	dB
$d_2$	second order distortion	note 1	_	_	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58.5	60	_	dBmV
F	noise figure	f = 50 MHz	_	<b> </b> -	6	dB
		f = 550 MHz	_	_	7	dB
		f = 650 MHz	_	_	7.5	dB
		f = 750 MHz	_	_	8	dB
		f = 860 MHz	_	1-	8.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	_	235	mA

### **Notes**

```
1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 805.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 860.5 MHz.
```

2. Measured according to DIN45004B:

$$\begin{split} &f_p = 851.25 \text{ MHz; } V_p = V_o; \\ &f_q = 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ &f_r = 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

3. The module normally operates at  $V_B$  = 24 V, but is able to withstand supply transients up to 30 V.

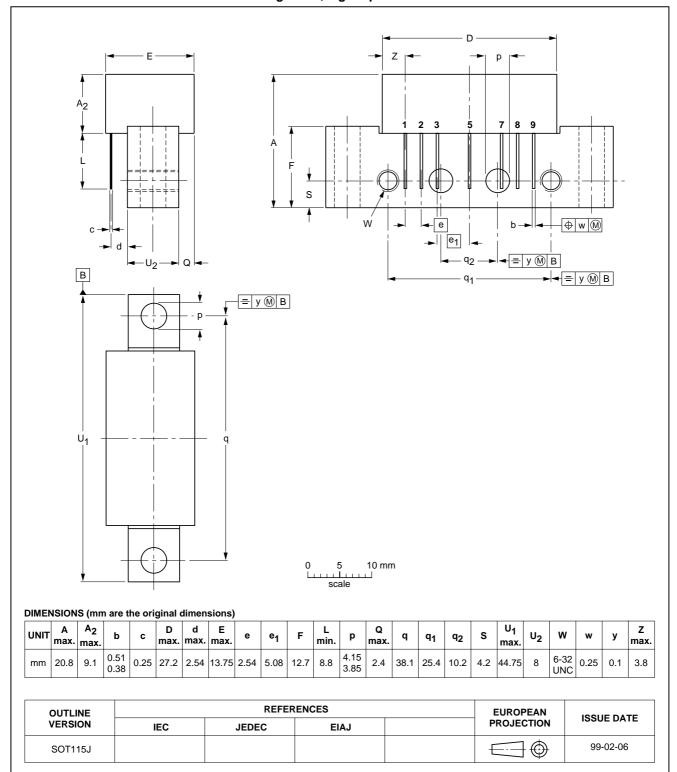
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#### **PACKAGE OUTLINE**

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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NOTES

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NOTES

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